

TRANSMITTAL

Electronic Version v1.1

Stylesheet Version v1.1.0

Title of Invention	METHOD OF PROGRAMMING A FLASH MEMORY THROUGH BOOSTING A VOLTAGE LEVEL OF A SOURCE LINE
Application Number :	
Date :	
First Named Applicant:	Ching-Sung Yang
Confirmation Number:	
Attorney Docket Number:	EMEP0061USA
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Documents being submitted:	Files
us-power-of-attorney-grant	EMEP0061-uspoat.xml us-power-of-attorney-grant.dtd us-power-of-attorney-grant.xsl
us-assignment	EMEP0061-usassn.xml us-assignment.xsl us-assignment.dtd EMEP0061ASS1.tif EMEP0061ASS2.tif
us-request	EMEP0061-usrequ.xml us-request.dtd us-request.xsl
us-fee-sheet	EMEP0061-usfees.xml us-fee-sheet.xsl us-fee-sheet.dtd
us-declaration	EMEP0061-usdecl.xml us-declaration.dtd us-declaration.xsl
application-body	EMEP0061-trans.xml us-application-body.xsl application-body.dtd wipo.ent mathml2.dtd mathml2-qname-1.mod isoamsa.ent isoamsb.ent isoamsc.ent isoamsn.ent isoamso.ent isoamsr.ent isogr3.ent isomfrk.ent isomopf.ent isomscr.ent isotech.ent isobox.ent isocyr1.ent isocyr2.ent isodia.ent isolat1.ent isolat2.ent isonum.ent isopub.ent mmlextra.ent mmlalias.ent soextblk.dtd emep0061usa-01.tif emep0061usa-02.tif emep0061usa-03.tif emep0061usa-04.tif

us-declaration

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Comments